

3V, 2400 MHz MEDIUM POWER SI MMIC AMPLIFIER

UPC2771T

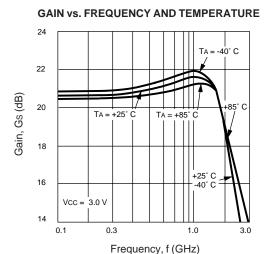
FEATURES

- HIGH GAIN: 20 dB at 900 to 1500 MHz Typical
- HIGH OUTPUT POWER: PSAT = +12.5 dBm at 900 MHz +11 dBm at 1500 MHz
- LOW BIAS VOLTAGE: 3.0 V Typical, 2.7 V Minimum
- SUPER SMALL PACKAGE
- TAPE AND REEL PACKAGING OPTION AVAILABLE

DESCRIPTION

The UPC2771T is a Silicon Monolithic integrated circuit which is manufactured using the NESAT III process. The NESAT III process produces transistors with ft approaching 20 GHz. This amplifier was designed as a driver amplifier for digital cellular applications. Operating on a 3 volt supply, this IC is ideally suited for hand-held, portable designs.

NEC's stringent quality assurance and test procedures ensure the highest reliability and performance.



ELECTRICAL CHARACTERISTICS (TA = 25° C, ZL = Zs = 50Ω , Vcc = 3.0 V)

PART NUMBER			UPC2771T T06			
PACKAGE OUTLINE						
SYMBOLS	PARAMETERS AND CONDITIONS		UNITS	MIN	TYP	MAX
Icc	Circuit Current (no signal)		mA		36	45
Gs	Small Signal Gain,	f = 900 MHz f = 1500 MHz	dB dB	19 17	21 20	24 23
fu	Upper Limit Operating Frequency (The gain at f∪ is 3 dB down from the gain at 100 MHz)	GHz	1.7	2.1	
P _{1dB}	1 dB Compressed Output Power,	f = 900 MHz f = 1500 MHz	dBm dBm	+9 +7	+11.5 +9.5	
Psat	Saturated Output Power,	f = 900 MHz f = 1500 MHz	dBm dBm		+12.5 +11	
NF	Noise Figure,	f = 900 MHz f = 1500 MHz	dB dB		6 6	7.5 7.5
RLIN	Input Return Loss,	f = 900 MHz f = 1500 MHz	dB dB	10 10	14 14	
RLout	Output Return Loss,	f = 900 MHz f = 1500 MHz	dB dB	6.5 5.5	9.5 8.5	
ISOL	Isolation,	f = 900 MHz f = 1500 MHz	dB dB	25 25	30 30	
OIP3	SSB OutputThird Order Intercept Point	f = 900, 902 MHz f = 1500, 1502 MHz	dBm dBm		+16 +13	

_California Eastern Laboratories

ABSOLUTE MAXIMUM RATINGS¹ (TA = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
Vcc	Supply Voltage	V	3.6
Icc	Total Supply Current	mA	77.7
Pin	Input Power	dBm	+13
Рт	Total Power Dissipation ²	mW	280
Тор	Operating Temperature	°C	-40 to +85
Тѕтс	Storage Temperature	°C	-55 to +150

Notes:

- Operation in excess of any one of these parameters may result in permanent damage.
- 2. Mounted on a 50 X 50 X 1.6 mm epoxy glass PWB (TA = 85°C).

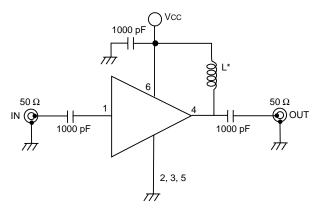
RECOMMENDED OPERATING CONDITIONS

SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
Vcc	Supply Voltage	V	2.7	3	3.3
Тор	Operating Temperature	°C	-40	+25	+85

TEST CIRCUIT

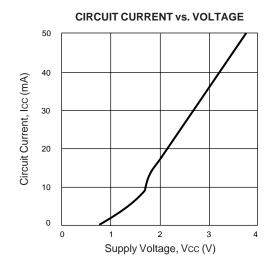
50

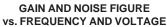
0

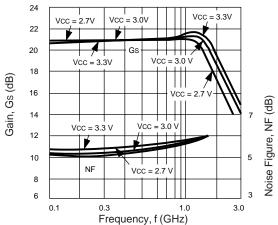


* This device is tested using a bias tee with typical series inductance, L = 1000 nH. In circuit applications, L = 50 nH is satisfactory at 900 MHz, and L = 10 nH is satisfactory at 1500 MHz.

TYPICAL PERFORMANCE CURVES (TA = 25°C)





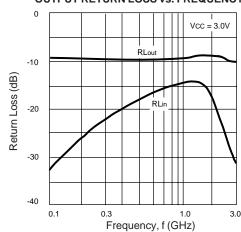


CIRCUIT CURRENT vs. TEMPERATURE

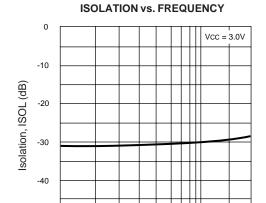
INPUT RETURN LOSS AND OUTPUT RETURN LOSS vs. FREQUENCY

Temperature (°C)

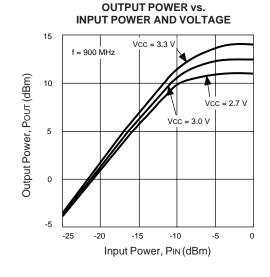
100

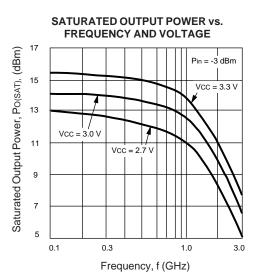


TYPICAL PERFORMANCE CURVES (TA = 25°)



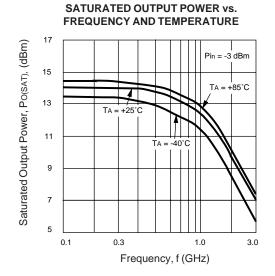
-50 L 0.1

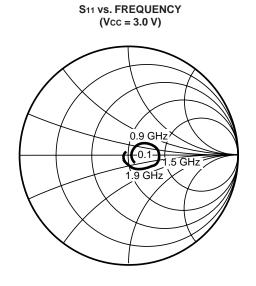


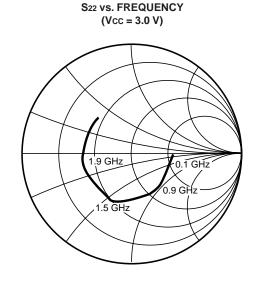


Frequency, f (GHz)

3.0



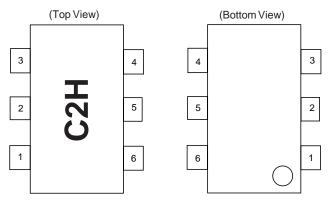




OUTLINE DIMENSIONS (Units in mm)

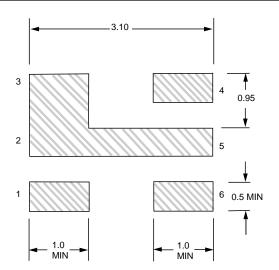
UPC2771T PACKAGE OUTLINE T06 2.8 +0.2 -0.3 -1.5 +0.2 -1.5 +0.2 -1.9±0.2 -1.1 +0.2 -1.

LEAD CONNECTIONS



- 1. INPUT
- 2. GND
- 3. GND
- 4. OUTPUT
- 5. GND
- 6. Vcc

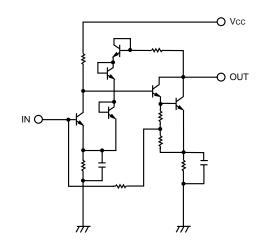
RECOMMENDED P.C.B. LAYOUT (Units in mm)



Note:

All dimensions are typical unless otherwise specified.

EQUIVALENT CIRCUIT



ORDERING INFORMATION

PART NUMBER	QTY
UPC2771T-E3	3K/Reel

Note

Embossed Tape, 8 mm wide.